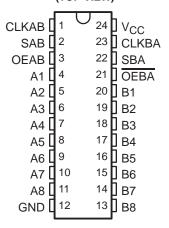
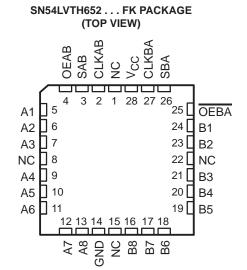
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- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- I_{off} and Power-Up 3-State Support Hot Insertion

SN54LVTH652 . . . JT OR W PACKAGE SN74LVTH652 . . . DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)



NC - No internal connection

description/ordering information

These bus transceivers and registers are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

ORDERING INFORMATION

TA	PACKA	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	0010 014	Tube	SN74LVTH652DW	IV/THOSO	
	SOIC – DW	Tape and reel	SN74LVTH652DWR	LVTH652	
	SOP - NS	Tape and reel	SN74LVTH652NSR	LVTH652	
-40°C to 85°C	SSOP – DB	Tape and reel	SN74LVTH652DBR	LXH652	
	T000D DW	Tube	SN74LVTH652PW	1.7/1/050	
	TSSOP – PW	Tape and reel	SN74LVTH652PWR	LXH652	
	TVSOP - DGV	Tape and reel	SN74LVTH652DGVR	LXH652	
	CDIP – JT	Tube	SNJ54LVTH652JT	SNJ54LVTH652JT	
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH652W	SNJ54LVTH652W	
	LCCC – FK	Tube	SNJ54LVTH652FK	SNJ54LVTH652FK	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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description/ordering information (continued)

The 'LVTH652 devices consist of bus-transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers.

Output-enable (OEAB and OEBA) inputs are provided to control the transceiver functions. Select-control (SAB and SBA) inputs are provided to select whether real-time or stored data is transferred. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between real-time and stored data. A low input selects real-time data and a high input selects stored data. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the 'LVTH652 devices.

Data on the A or B data bus, or both, can be stored in the internal D-type flip-flops by low-to-high transitions at the appropriate clock (CLKAB or CLKBA) inputs, regardless of the select- or enable-control pins. When SAB and SBA are in the real-time transfer mode, it is possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input; therefore, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last state.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor and OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking/current-sourcing capability of the driver.

This device is fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

FUNCTION TABLE

		INPU	TS			DATA	A 1/0†	ODERATION OR FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
L	Н	H or L	H or L	Χ	Х	Input	Input	Isolation
L	Н	\uparrow	\uparrow	X	X	Input	Input	Store A and B data
Х	Н	1	H or L	Х	Х	Input	Unspecified [‡]	Store A, hold B
Н	Н	\uparrow	\uparrow	X [‡]	X	Input	Output	Store A in both registers
L	Х	H or L	1	Χ	Х	Unspecified [‡]	Input	Hold A, store B
L	L	\uparrow	\uparrow	Χ	X [‡]	Output	Input	Store B in both registers
L	L	Χ	Х	Χ	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	Χ	Н	Output	Input	Stored B data to A bus
Н	Н	Χ	Х	L	Х	Input	Output	Real-time A data to B bus
Н	Н	H or L	Χ	Н	X	Input	Output	Stored A data to B bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A data to B bus and stored B data to A bus

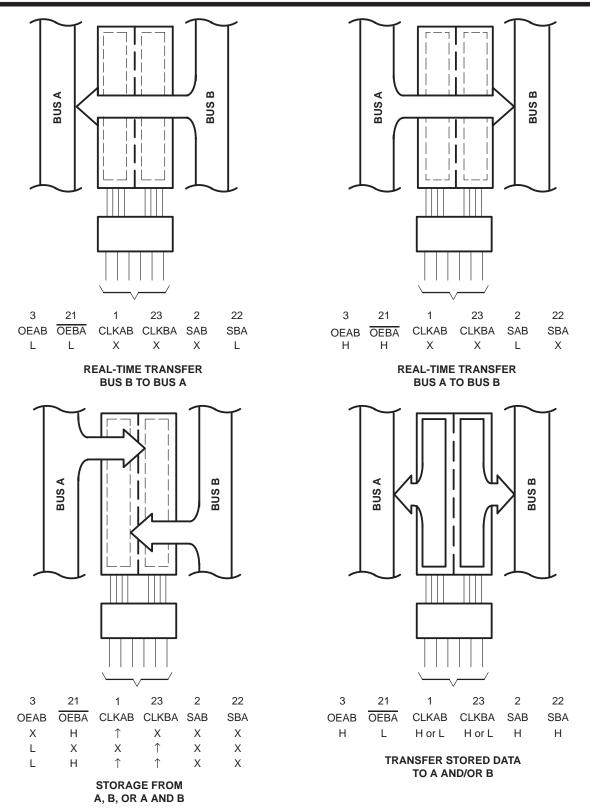
[†] The data-output functions can be enabled or disabled by a variety of level combinations at OEAB or OEBA. Data-input functions always are enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.



[‡] Select control = L; clocks can occur simultaneously.

Select control = H; clocks must be staggered to load both registers.

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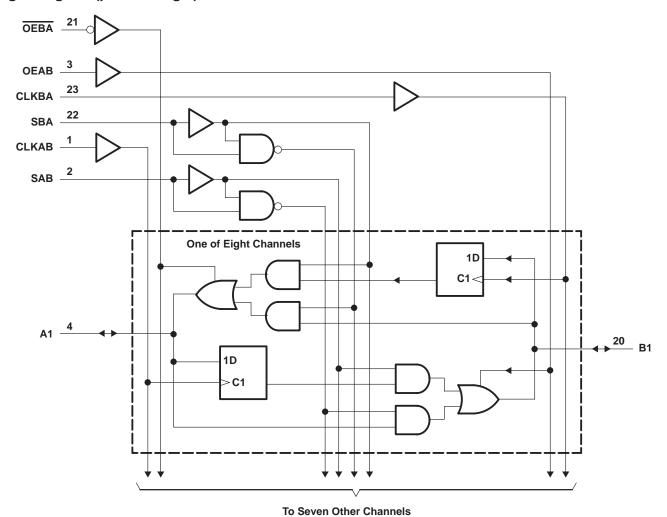
Pin numbers shown are for the DB, DGV, DW, JT, NS, PW, and W packages.

Figure 1. Bus-Management Functions



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logic diagram (positive logic)



Pin numbers shown are for the DB, DGV, DW, JT, NS, PW, and W packages.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		
Input voltage range, V _I (see Note 1)		
Voltage range applied to any output in the high-	impedance	
or power-off state, V _O (see Note 1)		
Voltage range applied to any output in the high	state, V _O (see Note 1)	\cdots -0.5 V to V _{CC} + 0.5 V
Current into any output in the low state, Io: SN	54LVTH652	96 mA
SN	74LVTH652)	128 mA
Current into any output in the high state, IO (see	Note 2): SN54LVTH652	8 mA
	SN74LVTH652	64 mA
Input clamp current, I _{IK} (V _I < 0)		–50 mA
Output clamp current, I _{OK} (V _O < 0)		
Package thermal impedance, θ_{JA} (see Note 3):	DB package	63°C/W
	DGV package	86°C/W
	DW package	46°C/W
	NS package	65°C/W
	PW package	88°C/W
Storage temperature range, T _{stg}		

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			SN54LV	TH652	SN74LV	/TH652	
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		2.7	3.6	2.7	3.6	V
V_{IH}	High-level input voltage		2	Z	2		V
V _{IL}	Low-level input voltage			0.8		0.8	V
VI	Input voltage		4	5.5		5.5	V
ІОН	High-level output current		6	-24		-32	mA
loL	Low-level output current		30	48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled	30	10		10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200		200		μs/V
T _A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

				SN	54LVTH	652	SN	74LVTH6	652	
PAF	RAMETER	TEST CO	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
VIK		$V_{CC} = 2.7 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0	.2		VCC-0	.2		
\ \/ - · ·		V _{CC} = 2.7 V,	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V
VOH		V 2.V	$I_{OH} = -24 \text{ mA}$	2						V
		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		V 27V	$I_{OL} = 100 \mu\text{A}$			0.2			0.2	
		V _{CC} = 2.7 V	$I_{OL} = 24 \text{ mA}$			0.5			0.5	
1			$I_{OL} = 16 \text{ mA}$			0.4			0.4	V
VOL		\/ 2\/	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V
		VCC = 3 V	$I_{OL} = 48 \text{ mA}$			0.55				
			$I_{OL} = 64 \text{ mA}$			2			0.55	
	Control innuts	V _{CC} = 3.6 V,	$V_I = V_{CC}$ or GND		, A	±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V		77	10			10	
lį	I _I A or B ports [‡]		V _I = 5.5 V		1	20			20	μА
		V _{CC} = 3.6 V	VI = VCC		2	1			1	
			V _I = 0	2	5	-5			-5	
I _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	9					±100	μΑ
		V 2.V	V _I = 0.8 V	75			75			
l _l (hold)	A or B ports	VCC = 3 V	V _I = 2 V	-75			-75			μА
, ,		V _{CC} = 3.6 V§	$V_{I} = 0 \text{ to } 3.6 \text{ V}$						±500	
lozpu		$V_{CC} = 0$ to 1.5 V, $V_{O} = 0$ OE/OE = don't care	0.5 to 3 V,			±100*			±100	μΑ
IOZPD		$V_{CC} = 1.5 \text{ V to } 0, V_{O} = 0$ OE/OE = don't care	0.5 to 3 V,			±100*			±100	μА
			Outputs high			0.19			0.19	
ICC		$V_{CC} = 3.6 \text{ V, } I_{O} = 0,$ $V_{I} = V_{CC} \text{ or GND}$	Outputs low			5			5	mA
		1 1 - 100 01 014D	Outputs disabled			0.19			0.19	
ΔICC¶		V _{CC} = 3 V to 3.6 V, One Other inputs at V _{CC} or C			_	0.2		_	0.2	mA
Ci		V _I = 3 V or 0			4			4		pF
Cio		V _O = 3 V or 0			9			9		pF

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

[‡]Unused terminals at V_{CC} or GND

[§] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

This is the increase in supply current for each input that is at the specified TTL voltage level, rather than VCC or GND.

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

				SN54L\	/TH652			SN74L\	/TH652		
			V _{CC} =	3.3 V 3 V	VCC =	2.7 V	V _{CC} =	3.3 V 3 V	VCC =	2.7 V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock frequency			150		150		150		150	MHz
t _W	Pulse duration, CLK high or low		3.3		3.3		3.3		3.3		ns
	Setup time,	Data high	1.3	202	1.6		1.2		1.5		
tsu	A or B before CLKAB↑ or CLKBA↑	Data low	1.9	6,64	2.6		1.6		2.2		ns
t _h	Hold time, A or B after CLKAB↑ or CLF	A or B after CLKAB↑ or CLKBA↑			1.2		0.8		0.8		ns

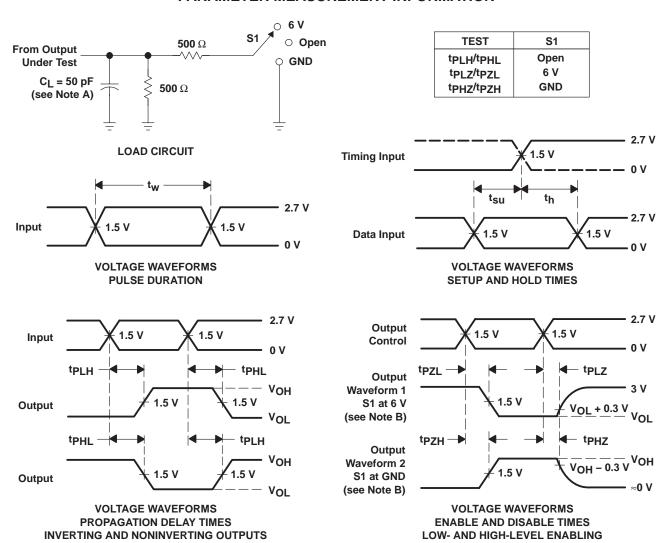
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 2)

				SN54L\	/TH652			SN7	4LVTH	652		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} =		VCC =	V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V			2.7 V	UNIT
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX	
f _{max}			150		150		150			150		MHz
t _{PLH}	CLKBA or	A or B	1.7	5		5.9	1.8	3.1	4.7		5.6	2.0
^t PHL	CLKAB	AOIB	1.7	5		5.9	1.8	3.1	4.7		5.6	ns
t _{PLH}	A or D	D or A	1.2	3.7		4.3	1.3	2.3	3.5		4.1	2.0
t _{PHL}	A or B	B or A	1.2	3.7	M;	4.3	1.3	2.4	3.5		4.1	ns
t _{PLH}	SBA or SAB‡	A D	1.4	5.2	1/4:	6.3	1.5	3.1	4.9		6	
t _{PHL}	SBA OF SAB+	A or B	1.4	5.2	140	6.3	1.5	3.4	4.9		6	ns
^t PZH	OEBA	٨	1	5.4	,	6.7	1.1	2.9	5.2		6.5	
t _{PZL}	OEBA	Α	1	5.4		6.7	1.1	3.1	5.2		6.5	ns
^t PHZ	OEBA	^	2.2	5.9		6.5	2.3	3.5	5.5		6.1	2.0
tPLZ	OEBA	Α	2.2	5.9		6.3	2.3	3.7	5.5		5.9	ns
^t PZH	OFAR	В	1.2	4.9		5.9	1.3	3	4.7		5.7	20
t _{PZL}	OEAB	В	1.2	4.9		5.9	1.3	3.3	4.7		5.7	ns
t _{PHZ}	OEAB	В	1.4	5.8		7	1.5	3.6	5.6		6.7	ns
t _{PLZ}	OLAB	В	1.4	5.9		6.6	1.5	3.7	5.6		6.3	115

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡]These parameters are measured with the internal output state of the storage register opposite that of the bus input.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \,\Omega$, $t_f \leq 2.5 \,$ ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74LVTH652DW	Active	Production	SOIC (DW) 24	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH652
SN74LVTH652DW.B	Active	Production	SOIC (DW) 24	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH652
SN74LVTH652PW	Active	Production	TSSOP (PW) 24	60 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH652
SN74LVTH652PW.B	Active	Production	TSSOP (PW) 24	60 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH652
SN74LVTH652PWR	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH652
SN74LVTH652PWR.B	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH652

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH652PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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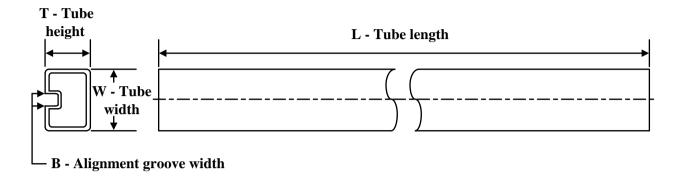
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH652PWR	TSSOP	PW	24	2000	353.0	353.0	32.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LVTH652DW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74LVTH652DW.B	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74LVTH652PW	PW	TSSOP	24	60	530	10.2	3600	3.5
SN74LVTH652PW.B	PW	TSSOP	24	60	530	10.2	3600	3.5



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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